

TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED MESA TYPE

2SD2550

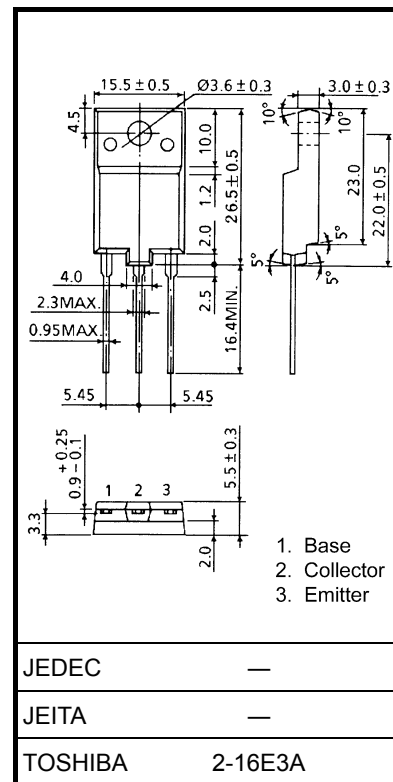
HORIZONTAL DEFLECTION OUTPUT FOR COLOR TVs

Unit: mm

- High Voltage : V_{CB0} = 1700 V
- Low Saturation Voltage : V_{CE (sat)} = 5.0 V (Max.)
- High Speed : t_f = 0.6 μs (Max.)
- Built-in Damper Type
- Collector Metal (Fin) is Fully Covered with Mold Resin.

ABSOLUTE MAXIMUM RATINGS (T_c = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V_{CB0}	1700	V
Collector-Emitter Voltage		V_{CEO}	600	V
Emitter-Base Voltage		V_{EB0}	5	V
Collector Current	DC	I_C	4	A
	Pulse	I_{CP}	8	
Base Current		I_B	2	A
Collector Power Dissipation		P_C	50	W
Junction Temperature		T_j	150	°C
Storage Temperature Range		T_{stg}	-55~150	°C

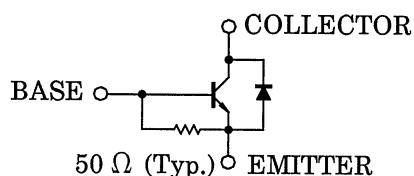


Weight: 5.5 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

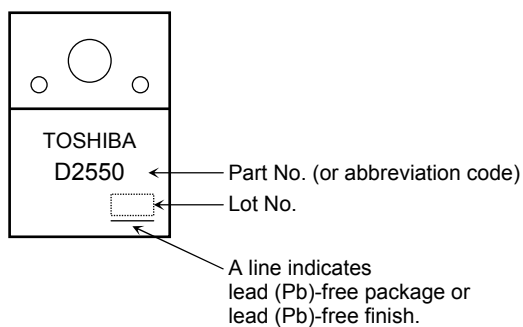
EQUIVALENT CIRCUIT

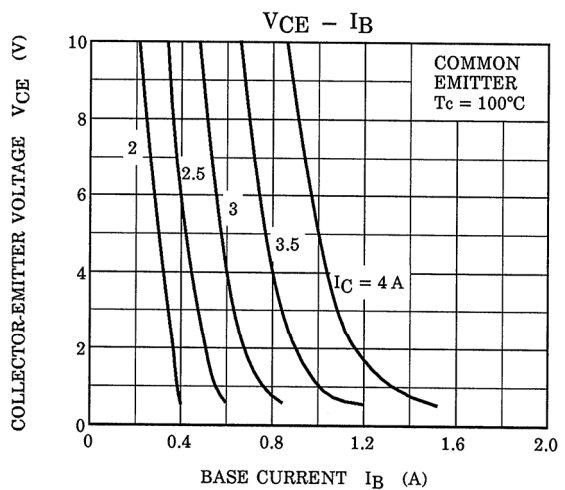
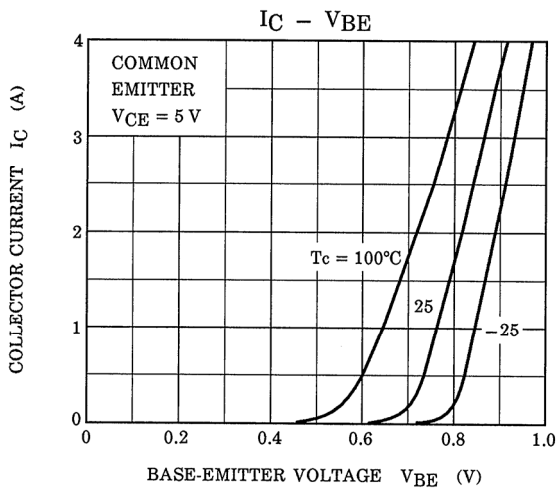
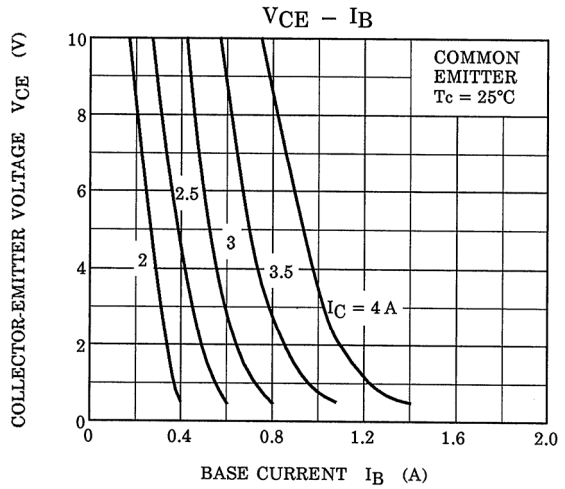
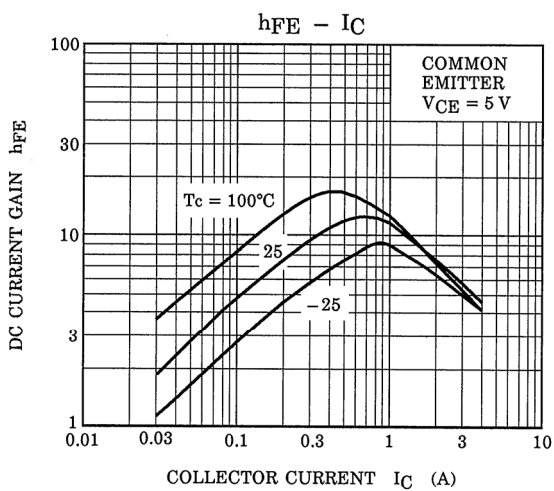
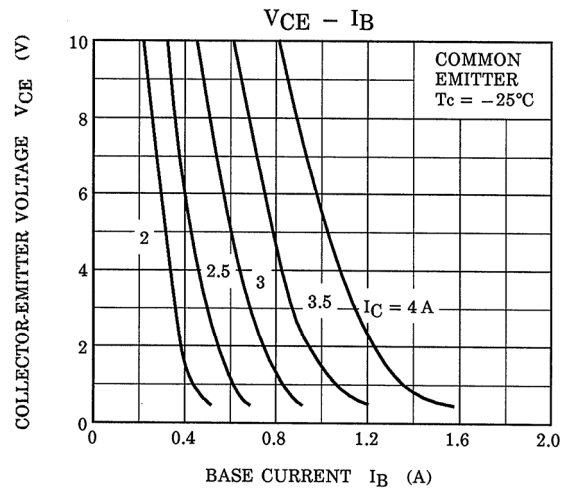
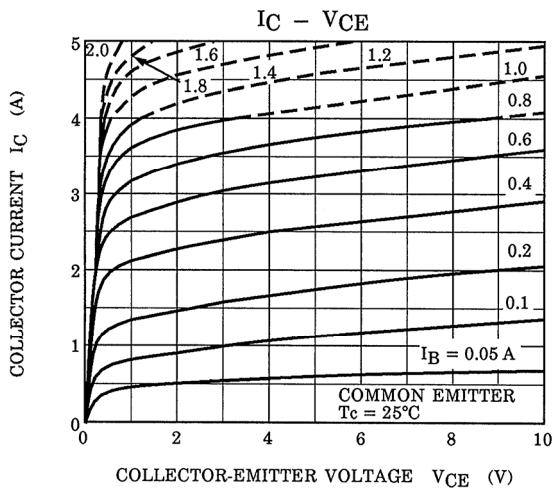


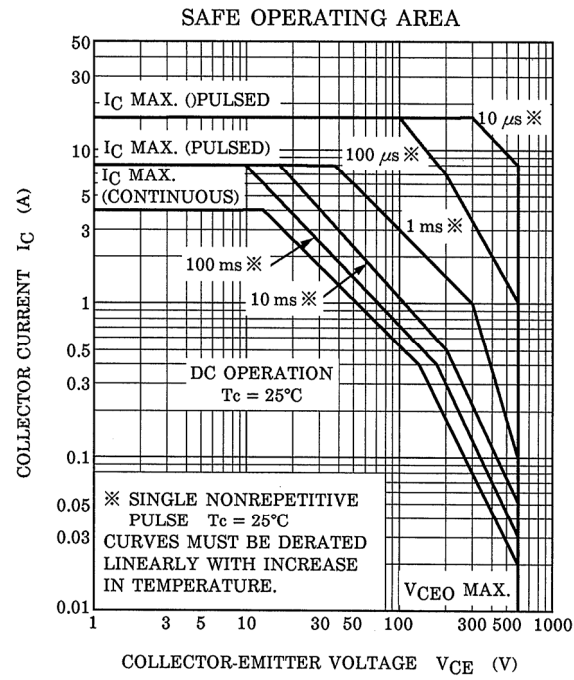
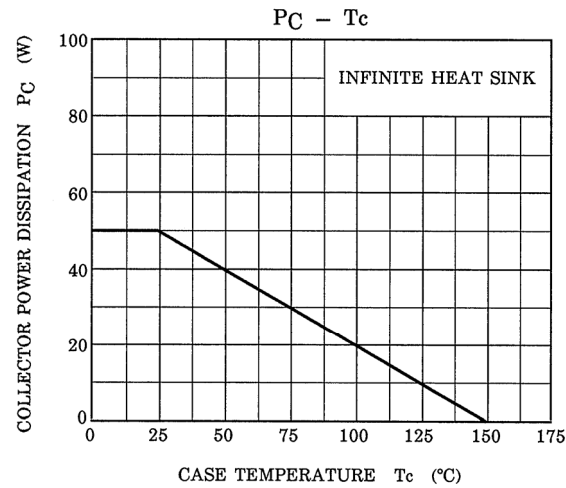
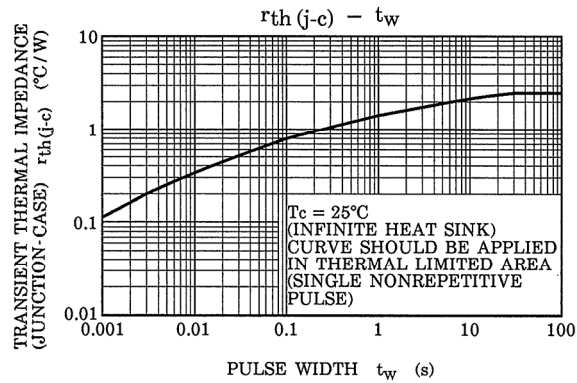
ELECTRICAL CHARACTERISTICS (T_C = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Collector Cut-off Current	I _{CBO}	V _{CB} = 1700 V, I _E = 0	—	—	1	mA
Emitter Cut-off Current	I _{EBO}	V _{EB} = 5 V, I _C = 0	66	—	200	mA
Emitter-Base Breakdown Voltage	V _(BR) EBO	I _C = 400 mA, I _B = 0	5	—	—	V
DC Current Gain	h _{FE}	V _{CE} = 5 V, I _C = 1 A	8	—	22	—
Collector-Emitter Saturation Voltage	V _{CE} (sat)	I _C = 3 A, I _B = 0.8 A	—	5	8	V
Base-Emitter Saturation Voltage	V _{BE} (sat)	I _C = 3 A, I _B = 0.8 A	—	—	1.2	V
Forward Voltage (Damper Diode)	V _F	I _F = 4 A	—	1.5	2.0	V
Transition Frequency	f _T	V _{CE} = 10 V, I _C = 0.1 A	—	3	—	MHz
Collector Output Capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	—	85	—	pF
Switching Time	Storage Time	I _{CP} = 3 A, I _{B1} (end) = 0.8 A f _H = 15.75 kHz	—	7.5	10	μs
	Fall Time		—	0.3	0.6	

MARKING







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